Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic-level compatible
- Very fast switching
- Trench MOSFET technology

3. Applications

- · Relay driver
- · High-speed line driver
- · High-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-30	٧	
V_{GS}	gate-source voltage			-20	-	20	V	
I _D	drain current	V _{GS} = -10 V; T _{amb} = 25 °C	[1]	-	=	-1.5	Α	
Static characte	Static characteristics							
R _{DSon}	drain-source on-state resistance	$V_{GS} = -10 \text{ V}; I_D = -1.5 \text{ A}; T_j = 25 \text{ °C}$		-	98	120	mΩ	

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D I
2	S	source		
3	D	drain		G P
			1 2	S 017aaa257
			SOT23	

6. Ordering information

Table 3. Ordering information

Type number Package						
	Name	Description	Version			
NXV90EP	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23			

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
NXV90EP	%5N

^{[1] % =} placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	T _j = 25 °C		-	-30	V
V_{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = -10 V; T _{amb} = 25 °C	[1]	-	-1.5	А
		V _{GS} = -10 V; T _{amb} = 100 °C	[1]	-	-1	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$		-	-6	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	340	mW
			[1]	-	470	mW
		T _{sp} = 25 °C		-	2.1	W
T _j	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drain	1 diode					•
Is	source current	T _{amb} = 25 °C	[1]	-	-0.4	А

- Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm². Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

30 V, P-channel Trench MOSFET

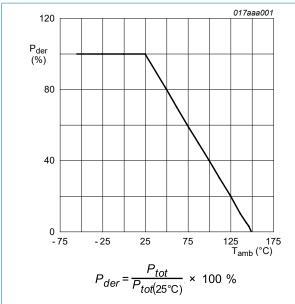


Fig. 1. Normalized total power dissipation as a function of ambient temperature

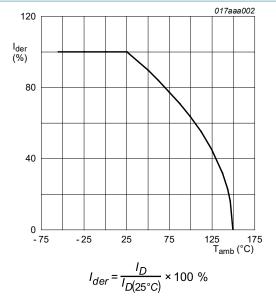


Fig. 2. Normalized continuous drain current as a function of ambient temperature

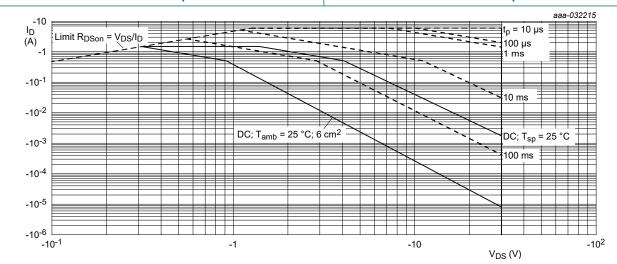


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

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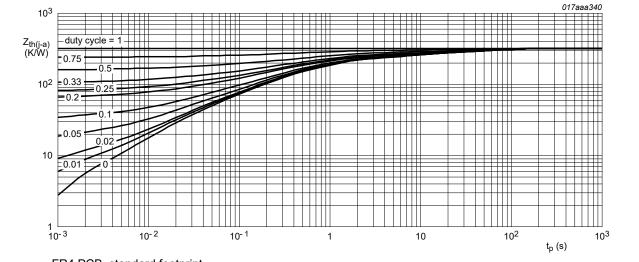
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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	325	370	K/W
junc	unction to ambient		[2]	-	230	260	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	50	60	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



FR4 PCB, standard footprint

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

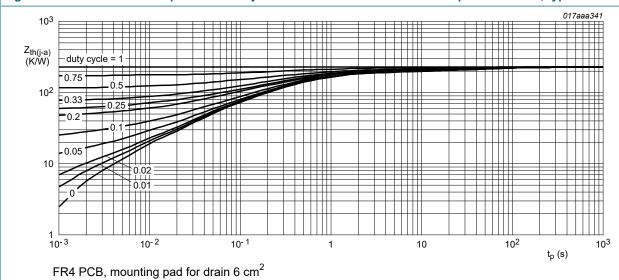


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

30 V, P-channel Trench MOSFET

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 μ A; V_{GS} = 0 V; T_j = 25 °C	-30	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = -250 \ \mu A; \ V_{DS} = V_{GS}; \ T_j = 25 \ ^{\circ}C$	-1	-1.8	-2.5	V
I _{DSS}	drain leakage current	V _{DS} = -30 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μΑ
I _{GSS}	gate leakage current	V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
		V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state	$V_{GS} = -10 \text{ V}; I_D = -1.5 \text{ A}; T_j = 25 \text{ °C}$	-	98	120	mΩ
	resistance	$V_{GS} = -10 \text{ V}; I_D = -1.5 \text{ A}; T_j = 150 \text{ °C}$	-	170	210	mΩ
		V_{GS} = -4.5 V; I_D = -1.2 A; T_j = 25 °C	-	135	200	mΩ
9 _{fs}	forward transconductance	$V_{DS} = -5 \text{ V}; I_D = -1.5 \text{ A}; T_j = 25 \text{ °C}$	-	2.8	-	S
R_G	gate resistance	f = 1 MHz	-	9.8	-	Ω
Dynamic ch	naracteristics			'	_	
Q _{G(tot)}	total gate charge	V_{DS} = -15 V; I_{D} = -1.5 A; V_{GS} = -10 V;	-	5.2	7.7	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.7	-	nC
Q_{GD}	gate-drain charge		-	1.2	-	nC
C _{iss}	input capacitance	V _{DS} = -15 V; f = 1 MHz; V _{GS} = 0 V;	-	252	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	39	-	pF
C _{rss}	reverse transfer capacitance	_	-	33	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = -15 \text{ V}; I_D = -1.5 \text{ A}; V_{GS} = -10 \text{ V};$	-	4	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 ^{\circ}C$	-	8	-	ns
t _{d(off)}	turn-off delay time		-	18	-	ns
t _f	fall time		-	7	-	ns
Source-drai	in diode					
V_{SD}	source-drain voltage	I _S = -0.4 A; V _{GS} = 0 V; T _j = 25 °C	-	-0.7	-1.2	V

30 V, P-channel Trench MOSFET

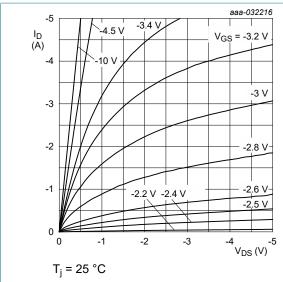
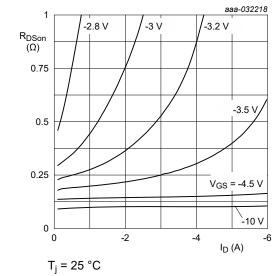
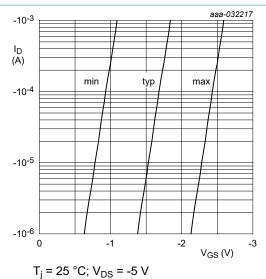


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values



Drain-source on-state resistance as a function Fig. 8. of drain current; typical values



Sub-threshold drain current as a function of Fig. 7. gate-source voltage

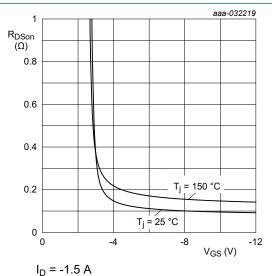


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

30 V, P-channel Trench MOSFET

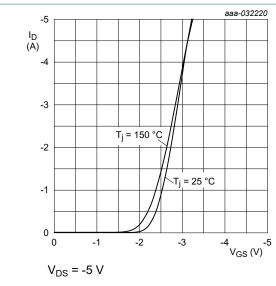


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

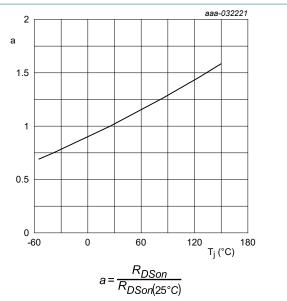


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

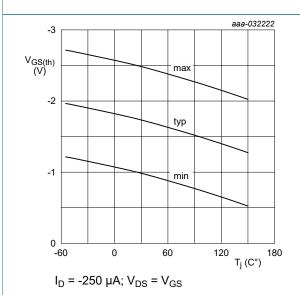
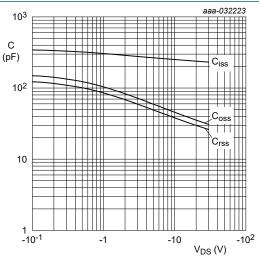


Fig. 12. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$

Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

30 V, P-channel Trench MOSFET

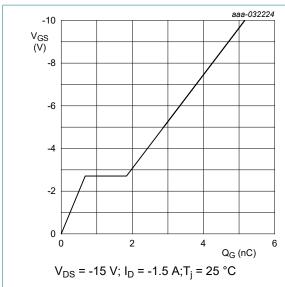


Fig. 14. Gate-source voltage as a function of gate charge; typical values

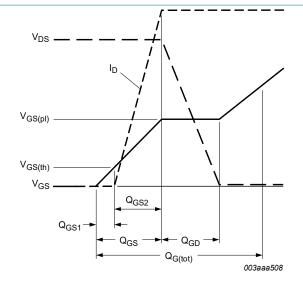


Fig. 15. Gate charge waveform definitions

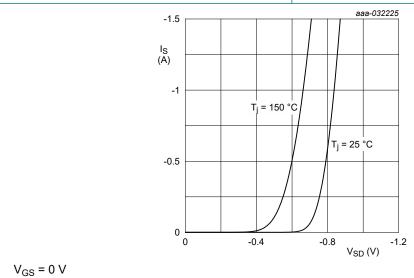
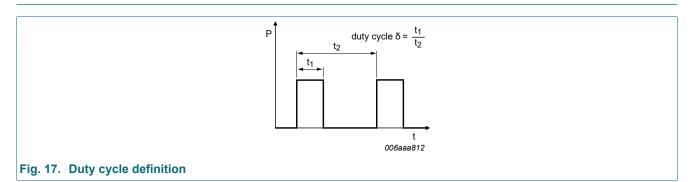


Fig. 16. Source current as a function of source-drain voltage; typical values

11. Test information

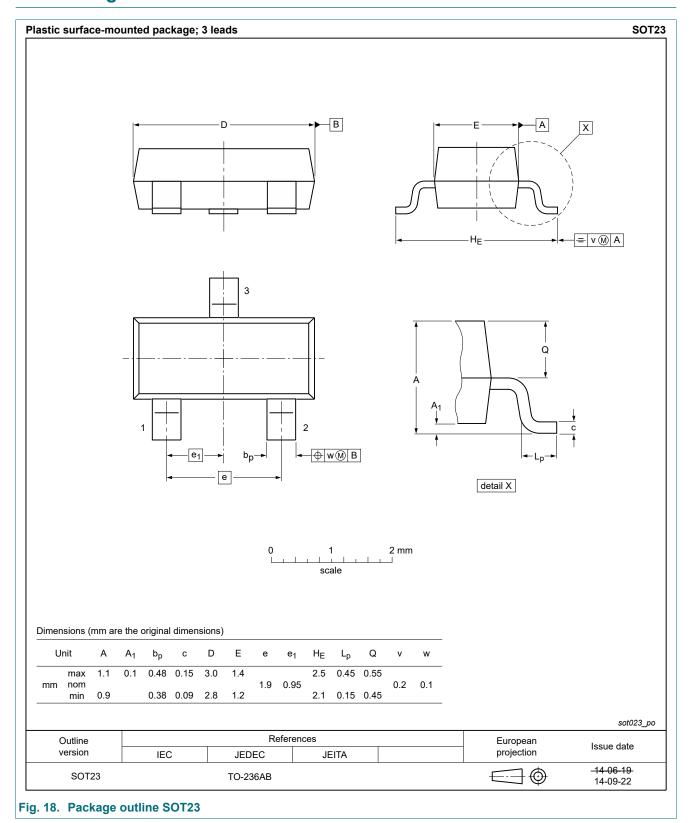


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8 / 12

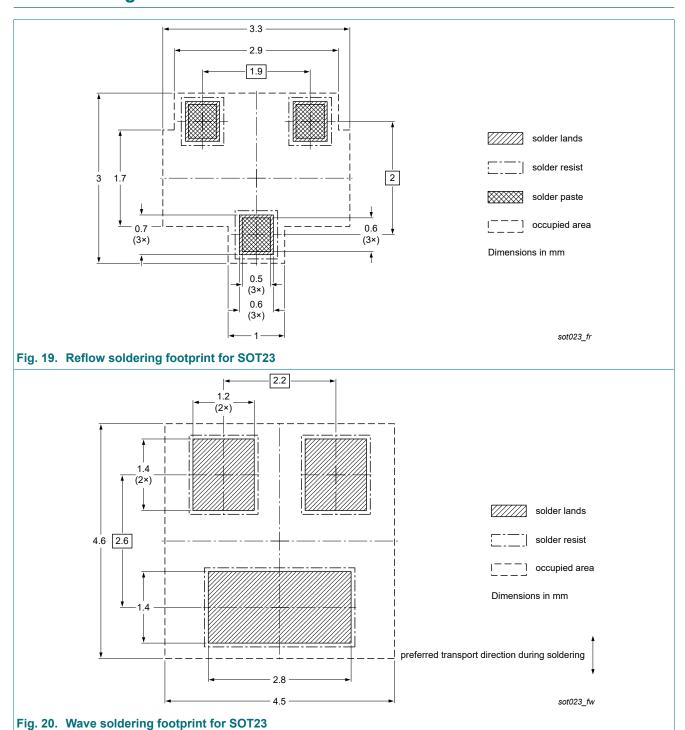
30 V, P-channel Trench MOSFET

12. Package outline



30 V, P-channel Trench MOSFET

13. Soldering



14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
NXV90EP v.1	20201019	Product	-	-

30 V, P-channel Trench MOSFET

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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30 V, P-channel Trench MOSFET

Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	. 2
9.	Thermal characteristics	. 4
10.	Characteristics	5
11.	Test information	8
12.	Package outline	9
13.	Soldering	10
14.	Revision history	10
	Legal information	

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